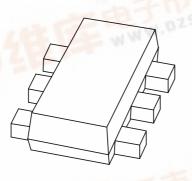
DISCRETE SEMICONDUCTORS

DATA SHEET



PEMB4 PNP resistor-equipped double transistor R1 = 10 kΩ, R2 = open

Preliminary specification

2001 Sep 14







PEMB4

FEATURES

- 300 mW total power dissipation
- Very small 1.6 mm \times 1.2 mm \times 0.55 mm ultra thin package
- · Excellent coplanarity due to straight leads
- Reduces number of components as replacement of two SC-75/SC-89 packaged transistors
- · Reduces required board space
- · Reduces pick and place costs.

APPLICATIONS

- General purpose switching and amplification
- · Inverter and interface circuits
- · Circuit driver.

DESCRIPTION

PNP resistor-equipped double transistor in a SOT666 plastic package.

MARKING

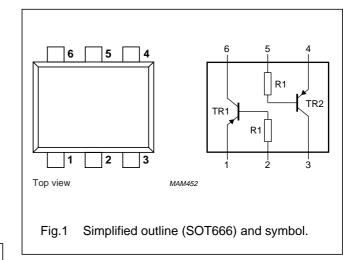
TYPE NUMBER	MARKING CODE
PEMB4	B4

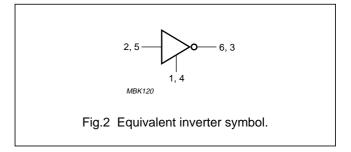
PINNING

PIN	DESCRIPTION			
1, 4	emitter	TR1; TR2		
2, 5	base	TR1; TR2		
6, 3	collector	TR1; TR2		

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
V _{CEO}	collector-emitter voltage	-50	٧
I _{CM}	peak collector current	-100	mA
TR1	PNP	_	_
TR2	PNP	_	_
R1	bias resistor	10	kΩ





PEMB4

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT	
Per transistor						
V _{CBO}	collector-base voltage	open emitter	_	-50	V	
V _{CEO}	collector-emitter voltage	open base	_	-50	V	
V _{EBO}	emitter-base voltage	open collector	_	- 5	V	
Io	output current (DC)		_	-100	mA	
I _{CM}	peak collector current		_	-100	mA	
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	200	mW	
T _{stg}	storage temperature		-65	+150	°C	
Tj	junction temperature		_	150	°C	
T _{amb}	operating ambient temperature		-65	+150	°C	
Per device)					
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	300	mW	

Note

1. Transistor mounted on an FR4 printed-circuit board.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	notes 1 and 2	416	K/W

Notes

- 1. Transistor mounted on an FR4 printed-circuit board.
- 2. The only recommended soldering method is reflow soldering.

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Per transis	stor					,
I _{CBO}	collector cut-off current	I _E = 0; V _{CB} = -50 V	_	_	-100	nA
I _{CEO}	collector cut-off current	I _B = 0; V _{CE} = -50 V	_	_	-1	μΑ
		$I_B = 0$; $V_{CE} = -30 \text{ V}$; $T_j = 150 ^{\circ}\text{C}$	_	_	-50	μΑ
I _{EBO}	emitter cut-off current	$I_C = 0; V_{EB} = -5 \text{ V}$	_	_	-100	nA
h _{FE}	DC current gain	$I_C = -1 \text{ mA}; V_{CE} = -5 \text{ V}$	100	_	600	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -10 \text{ mA}; I_B = -0.5 \text{ mA}$	_	_	-300	mV
R1	input resistor		7	10	13	kΩ
C _c	collector capacitance	$I_E = i_e = 0$; $V_{CB} = -10 \text{ V}$; $f = 1 \text{ MHz}$	_	_	5	pF

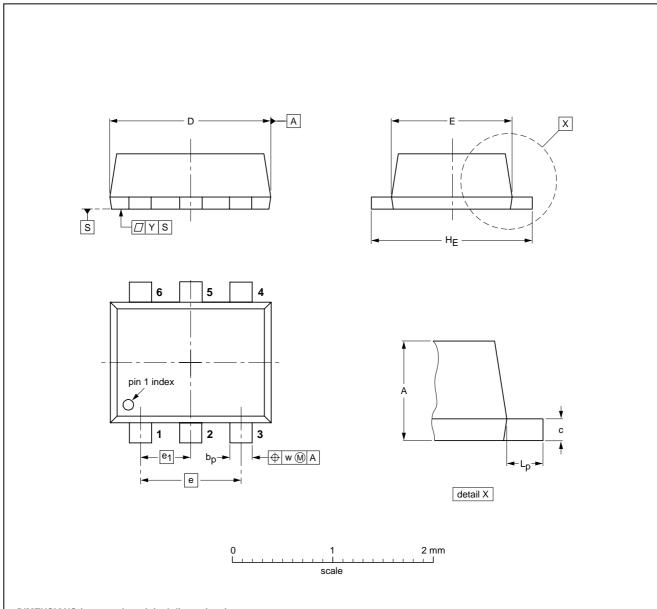
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PACKAGE OUTLINE

Plastic surface mounted package; 6 leads

SOT666



DIMENSIONS (mm are the original dimensions)

UNIT	A	bp	С	D	E	e	e ₁	HE	L _p	w	у
mm	0.6 0.5	0.27 0.17	0.18 0.08	1.7 1.5	1.3 1.1	1.0	0.5	1.7 1.5	0.3 0.1	0.1	0.1

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT666						-01-01-04 01-08-27	

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DATA SHEET STATUS

DATA SHEET STATUS(1)	PRODUCT STATUS ⁽²⁾	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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Notes

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